Clock OSC   SG5032VAN

SEIKO EPSON CORPORATION

Product name   SG5032VAN   156.250000MHz KJGA
Product Number / Ordering code   X1G0042610006xx

Please refer to the 9.Packing information about xx (last 2 digits)

Output waveform LVDS
Pb free / Complies with EU RoHS directive
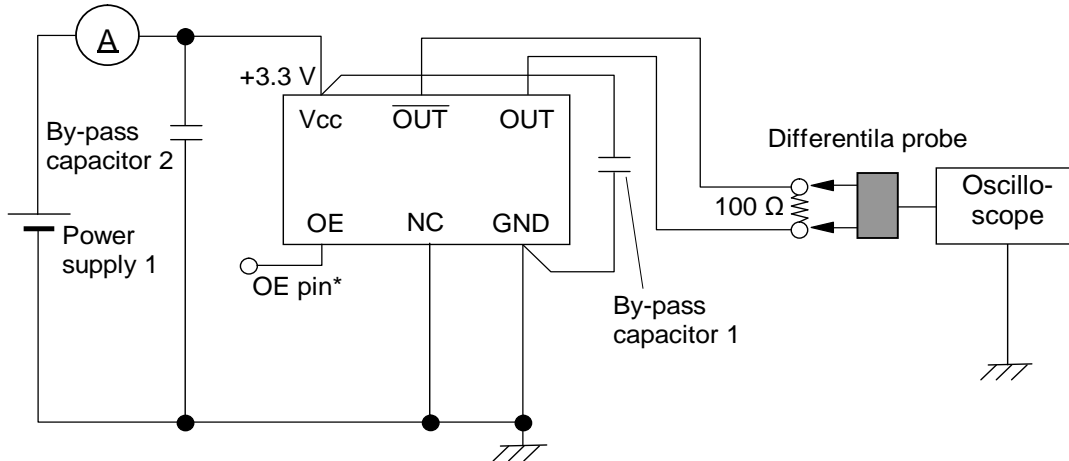Reference weight Typ. 52 mg

1.Absolute maximum ratings

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions / Remarks
Maximum supply voltage	Vcc-GND	-0.3	-	+4	V	-
Storage temperature	T_stg	-40	-	+125	ºC	Storage as single product
Input voltage	Vin	-0.3	-	Vcc+0.3	V	ST or OE Terminal

2.Specifications(characteristics)

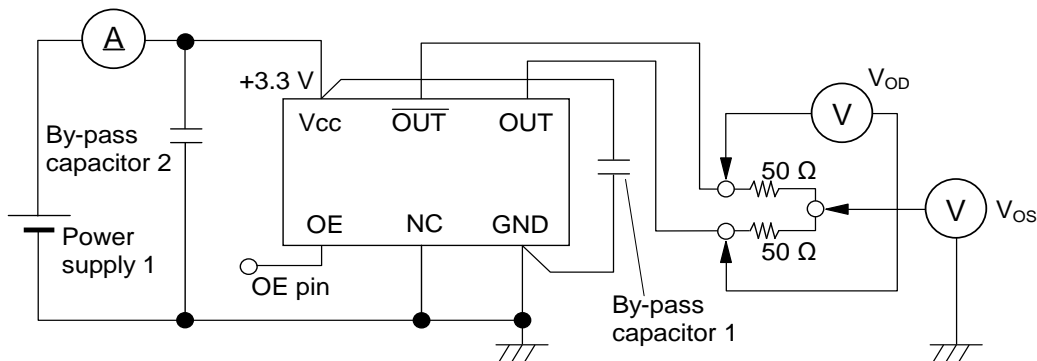| Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions / Remarks
Output frequency	f_0	-	156.2500	-	MHz	
Supply voltage	Vcc	2.25	-	3.63	V	-
Operating temperature	T_use	-40	-	+85	ºC	-
Frequency tolerance	f_tol	-50	-	50	$\times 10^{-6}$	-
Current consumption	Icc	-	-	30	mA	OE=Vcc L_LVDS=100 ohm
Stand-by current	I_std	-	-	0.0	mA	-
Disable current	I_dis	-	-	20.0	mA	OE=GND
Symmetry	SYM	45	-	55	%	-
Output voltage(LVDS)	V_{OD}	250	-	450	mV	-
	dV_{OD}	-	-	50	mV	-
	Vos	1.15	-	1.35	V	-
	dVos	-	-	150	mV	-
Output load condition(LVDS)	L_LVDS	-	100	-	Ω	-
Input voltage	V_{IH}	0.7Vcc	-	-		-
	V_{IL}	-	-	0.3Vcc		-
Rise time	t_r	-	-	300	ps	-
Fall time	tf	-	-	300	ps	-
Start-up time	t_str	-	-	3	ms	-
Jitter	t_{DJ}	-	15.3	-	ps	Deterministic Jitter Vcc=2.5V
	T_{RJ}	-	2.2	-	ps	Random Jitter Vcc=2.5V
	t_{RMS}	-	6.4	-	ps	δ(RMS of total distribution) Vcc=2.5V
	t_{p-p}	-	33.3	-	ps	Peak to Peak Vcc=2.5V
	t_{acc}	-	5.7	-	ps	-
Phase jitter	t_{PJ}	-	0.28	-	ps	Off set Frequency: 12kHz to 20MHz Vcc=2.5V
Phase noise	L(f)	-	-	-	dBc/Hz	-
		-	-86	-	dBc/Hz	Off set 10Hz Vcc=3.3V
		-	-111	-	dBc/Hz	Off set 100Hz Vcc=3.3V
		-	-123	-	dBc/Hz	Off set 1kHz Vcc=3.3V
		-	-131	-	dBc/Hz	Off set 10kHz Vcc=3.3V
		-	-138	-	dBc/Hz	Off set 100kHz Vcc=3.3V
		-	-138	-	dBc/Hz	Off set 1MHz Vcc=3.3V
Frequency aging	f_age	-5	-	5	$\times 10^{-6}$/Year	25℃,1stYear
		-	-	-		-

3.Test circuit

1) To observe waveform and current (case 1)

* The lines from OUT and $\overline{OUT}$ pin are same length.

* To measure the disable current, OE pin is connected to GND

2) To observe waveform and current (case 2)

* The lines from OUT and $\overline{OUT}$ pin are same length.

3) Measurement condition

A) Oscilloscope

•Bandwidth should be 5 times higher than DUT's output frequency (4 GHz).

•Probe ground should be placed closely from test point and lead length should be as short as possible.

B) By-pass capacitor 1 (approx. 0.01 µF to 0.1 µF) places closely between Vcc and GND.

C) By-pass capacitor 2 (approx. 10 µF) places closely between power supply terminals on the board.
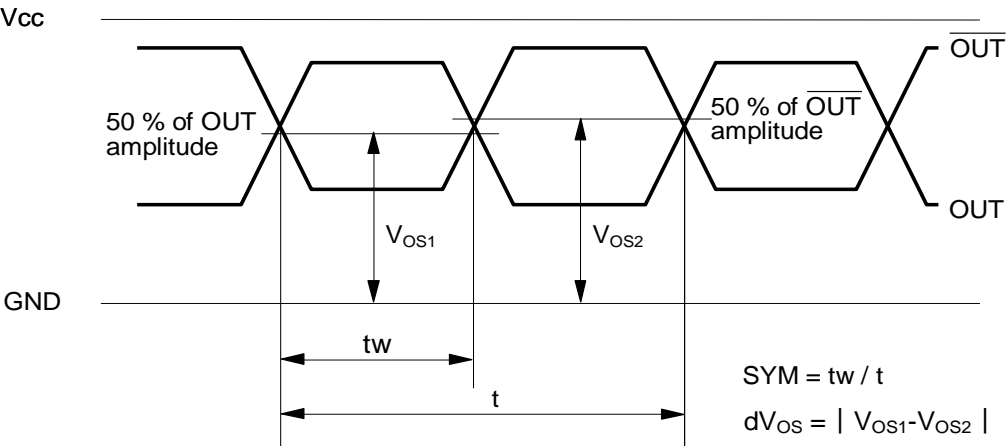
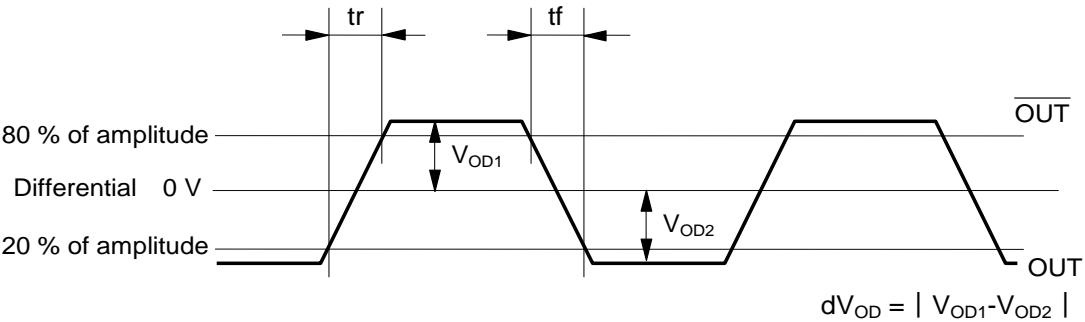D) Use the current meter whose internal impedance value is small.

E) Power supply

• Start up time (0 Vg90 %Vcc) of power source should be more than 150 µs and

slew rate should be less than 19.8 mV/µs.

• Impedance of power supply should be as low as possible.

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4.Timing chart

Each output waveform (OUT, and $\overline{\text{OUT}}$)

Vcc

50 % of OUT amplitude

$\overline{\text{OUT}}$

50 % of $\overline{\text{OUT}}$ amplitude

OUT

V_{OS1} V_{OS2}

GND

tw

t

$$SYM = tw / t$$
$$dV_{OS} = |\, V_{OS1} - V_{OS2}\,|$$

Differential output waveform (OUT – $\overline{\text{OUT}}$)

tr   tf

80 % of amplitude

$\overline{\text{OUT}}$

V_{OD1}

Differential   0 V

V_{OD2}

20 % of amplitude

OUT

$$dV_{OD} = |\, V_{OD1} - V_{OD2}\,|$$

5.External dimensions	(Unit: mm)

5.0±0.2   1.0±0.2

#6 #5 #4

SG5032

#1 #2 #3

3.2±0.2

2.54

#1 #2 #3

1.0
1.2   C0.3

#6 #5 #4

0.91
0.64

Pin	Connection
1	OE
2	N.C.
3	GND
4	OUT
5	$\overline{\text{OUT}}$
6	VCC

OE pin = HIGH : Specified frequency output
OE pin = LOW : Output is high impedance
#3 is connected to the cover.
Not to scale.

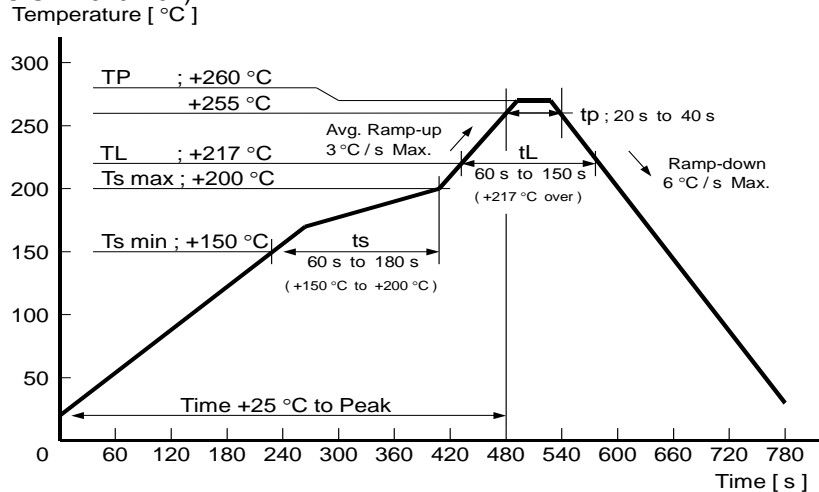| 6.Footprint(Recommended)	(Unit: mm)

0.89   0.89

#6   #5   #4

1.60

2.60

#1   #2   #3

2.54

To maintain stable operation, provide a 0.01uF to 0.1uF by-pass capacitor at a location as near as possible to the power source terminal of the crystal product (between Vcc - GND).

7.Reflow profile

Reflow condition (Follow of JEDEC STD-020D.01)

Temperature [°C]

TP ; +260 °C
+255 °C
tp ; 20 s to 40 s

TL ; +217 °C
Avg. Ramp-up
3 °C / s Max.
tL
Ts max ; +200 °C
60 s to 150 s
(+217 °C over)
Ramp-down
6 °C / s Max.

Ts min ; +150 °C
ts
60 s to 180 s
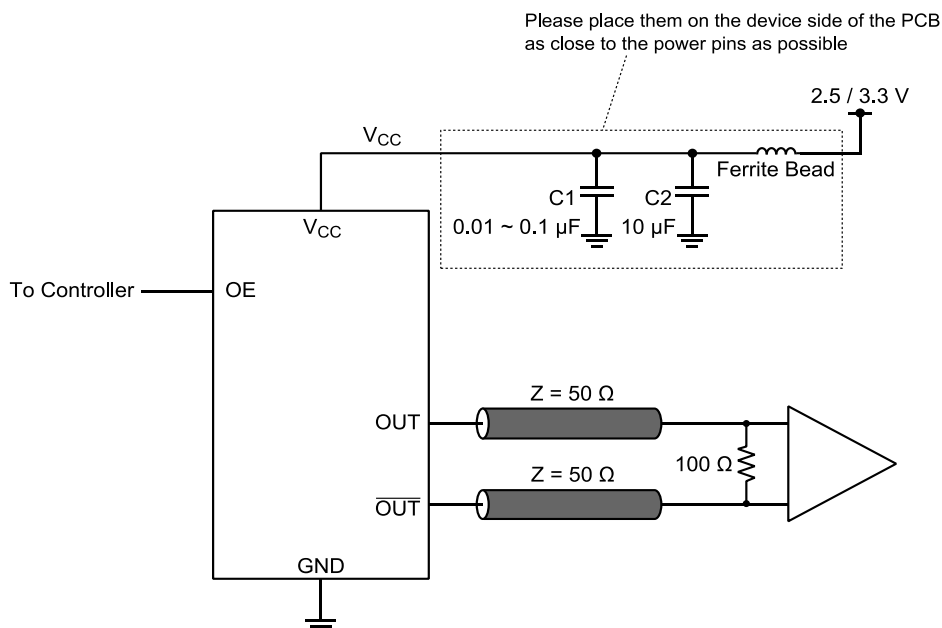(+150 °C to +200 °C)

Time +25 °C to Peak

Time [s]

8.Example of schematic layout

This figure shows an example of this product's application schematic.
As with any high speed analog circuitry, the power supply pins for this device are vulnerable to noise. In order to achieve optimum jitter performance, power isolation with filter device is required for power supply pins.
In order to achieve best performance of the power isolation filter, it is recommended that the filter composing devices is placed on the device side of the PCB as close to the power pins as possible. The component value of this filter is just an example, it may have to be adjusted.

Please place them on the device side of the PCB
as close to the power pins as possible

2.5 / 3.3 V

V_{CC}

Ferrite Bead

C1
C2
$0.01 \sim 0.1$ μF
10 μF

V_{CC}

To Controller — OE

OUT
Z = 50 Ω
100 Ω

$\overline{OUT}$
Z = 50 Ω

GND

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* By-pass capacitor (approx. 0.01 μF to 0.1 μF) places closely between Vcc and GND.
* By-pass capacitor (approx. 10 μF) places closely between power supply terminals on the board.
* Please design the two output lines by characteristic impedance 100 Ω and same length, and try to make the output lines as short as possible.

9.Packing information

[1]Product number last 2 digits code(xx) description   The recommended code is "00"

X1G0042610006xx

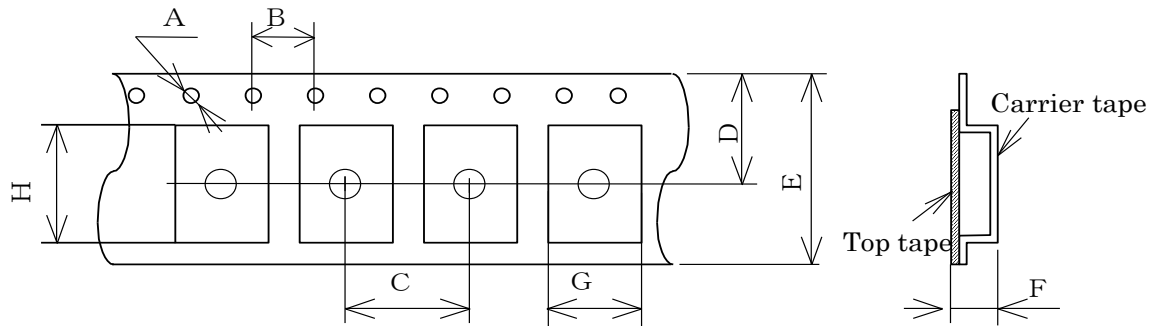| Code	Condition	Code	Condition
01	Any Q'ty vinyl bag(Tape cut)	13	500pcs / Reel
11	Any Q'ty / Reel	00	1000pcs / Reel
12	250pcs / Reel		

[2] Taping specification
Subject to EIA-481 & IEC-60286

(1) Tape dimensions
Material of the Carrier Tape : PS
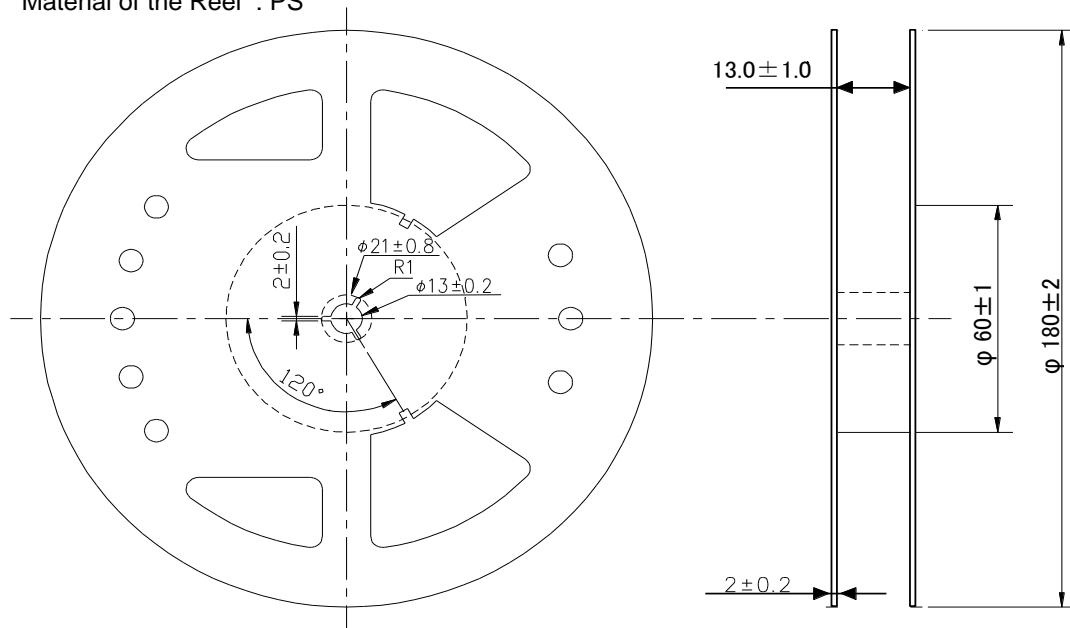Material of the Top Tape : PET+PE

Unit: mm

Symbol	A	B	C	D	E	F	G	H
Value	φ1.5 +0.1/-0	4.0±0.1	8.0±0.1	7.25±0.2	12.0±0.2	1.40±0.1	3.5±0.1	5.4±0.1

(2) Reel dimensions
Center material : PS
Material of the Reel : PS

13.0±1.0

φ21±0.8
R1
φ13±0.2
2±0.2
120°

φ60±1
φ180±2
2±0.2

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